



## FEATURES

- \* Low forward voltage drop
- \* High current capability
- \* High reliability
- \* High surge current capability
- \* High speed switching

## MECHANICAL DATA

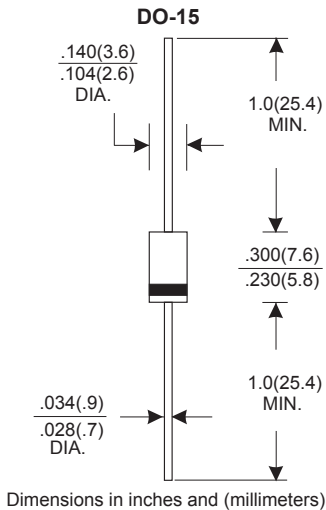
- \* Case: Molded plastic
- \* Epoxy: UL 94V-0 rate flame retardant
- \* Lead: Axial leads, solderable per MIL-STD-202, method 208 guaranteed
- \* Polarity: Color band denotes cathode end
- \* Mounting position: Any
- \* Weight: 0.40 grams
- \* Both normal and Pb free product are available:
- \* Normal: 80~95%Sn, 5~20%Pb
- \* Pb free: 99 Sn above can meet Rohs environment substance directive request

## VOLTAGE RANGE

50 to 1000 Volts

## CURRENT

1.5 Ampere



## MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating 25°C ambient temperature unless otherwise specified.  
 Single phase half wave, 60Hz, resistive or inductive load.  
 For capacitive load, derate current by 20%.

TYPE NUMBER	HER151	HER152	HER153	HER154	HER155	HER156	HER157	HER158	UNITS
Maximum Recurrent Peak Reverse Voltage	50	100	200	300	400	600	800	1000	V
Maximum RMS Voltage	35	70	140	210	280	420	560	700	V
Maximum DC Blocking Voltage	50	100	200	300	400	600	800	1000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length at Ta=50°C	1.5								A
Peak Forward Surge Current, 8.3 ms single half sine-wave superimposed on rated load (JEDEC method)	50								A
Maximum Instantaneous Forward Voltage at 1.5A	1.0			1.3		1.7			V
Maximum DC Reverse Current Ta=25°C	5.0								µA
at Rated DC Blocking Voltage Ta=100°C	150								µA
Maximum Reverse Recovery Time (Note 1)	50					75			nS
Typical Junction Capacitance (Note 2)	30								pF
Operating and Storage Temperature Range Tj, Tstg	-65 — +150								°C

### NOTES:

1. Reverse Recovery Time test condition: IF=0.5A, IR=1.0A, IRR=0.25A
2. Measured at 1MHz and applied reverse voltage of 4.0V D.C.



FIG.1-TYPICAL FORWARD CHARACTERISTICS

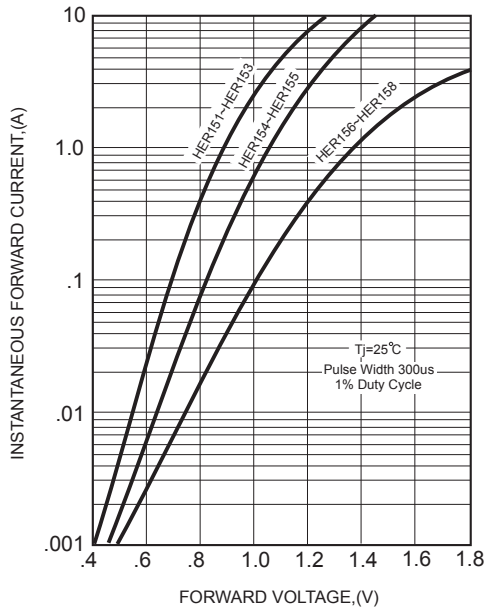


FIG.2-TYPICAL FORWARD CURRENT DERATING CURVE

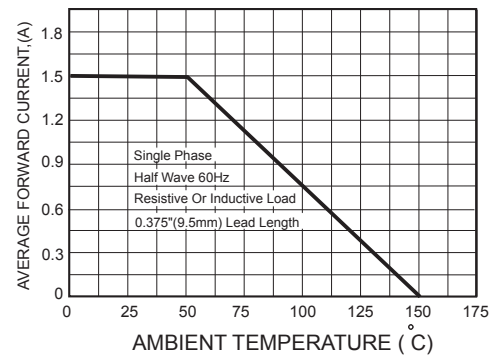
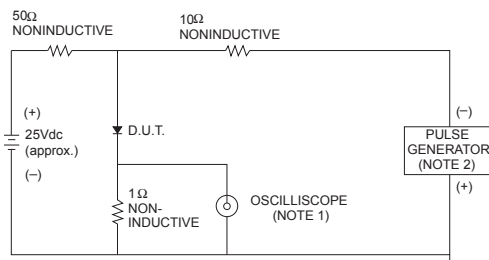


FIG.3- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTICS



NOTES: 1. Rise Time = 7ns max., Input Impedance = 1 megohm, 22pF.  
2. Rise Time = 10ns max., Source Impedance = 50 ohms.

FIG.4-MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

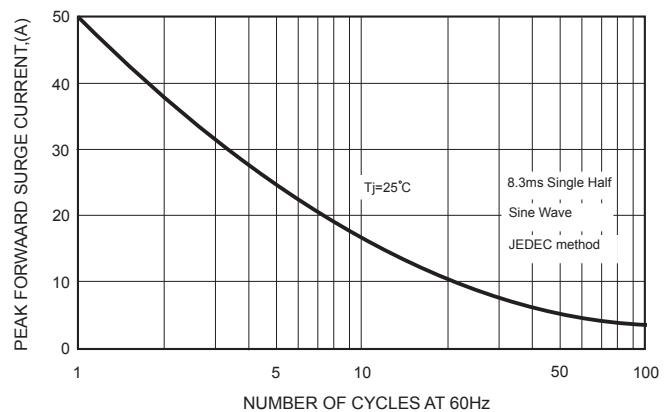


FIG.5-TYPICAL JUNCTION CAPACITANCE

